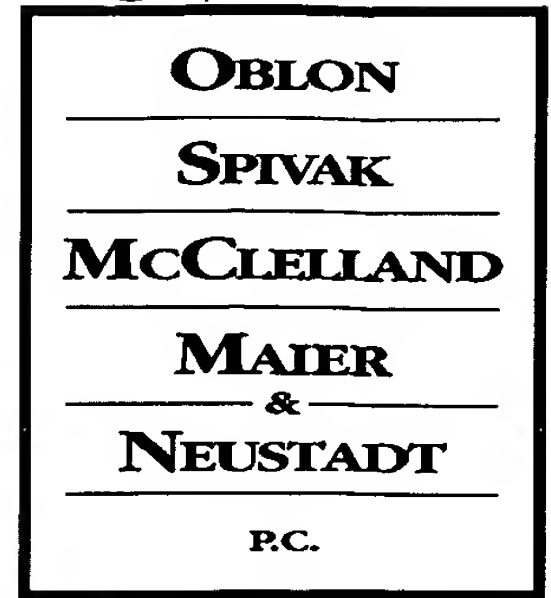




Docket No.: 240627US0

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313



ATTORNEYS AT LAW

RE: Application Serial No.: 10/625,512

Applicants: Yoshifumi INOUE

Filing Date: July 24, 2003

For: FLAME RETARDANT EPOXY RESIN
COMPOSITION, SEMICONDUCTOR
ENCAPSULATING MATERIAL USING SAME, AND
RESIN ENCAPSULATED SEMICONDUCTOR
DEVICE

Group Art Unit: 1712

Allowed: February 1, 2006

Examiner: ROBERTSON, J.

SIR:

Attached hereto for filing are the following papers:

AMENDMENT UNDER 37 CFR 1.312

Our check in the amount of \$0.00 is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.
Norman F. Oblon


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Application No. 10/625,512
Amendment under 37 CFR 1.312

DOCKET NO: 240627US0



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :

YOSHIFUMI INOUE

: EXAMINER: ROBERTSON, J.

SERIAL NO: 10/625,512

: ALLOWED: FEBRUARY 1, 2006

FILED: JULY 24, 2003

: GROUP ART UNIT: 1712

FOR: FLAME RETARDANT EPOXY
RESIN COMPOSITION,
SEMICONDUCTOR ENCAPSULATING
MATERIAL USING SAME, AND RESIN
ENCAPSULATED SEMICONDUCTOR
DEVICE

AMENDMENT UNDER 37 CFR 1.312

COMMISSIONER FOR PATENTS
P. O. BOX 1450
ALEXANDRIA, VIRGINIA 22313-1450

SIR:

Please amend the above-identified application under 37 CFR 1.312 as follows:

Amendments to the Claims are reflected in the listing of claims which begins on
page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.